



NPN Low Vce(sat) Transistor

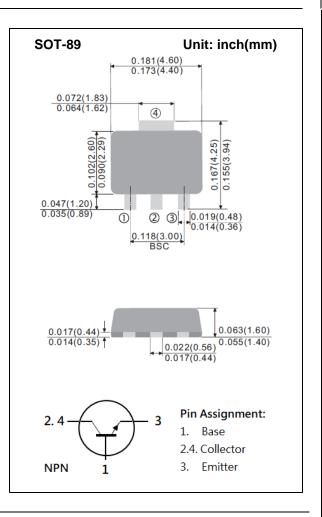
Voltage 100V Current

Features

- Silicon NPN epitaxial type
- Low Vce(sat) 0.35V(max)@Ic/Ib= 500mA / 50mA
- High collector current capability
- Excellent DC current gain characteristics
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 Standard
- PNP complement: BCX53-16-AU

Mechanical Data

- Case: SOT-89 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.002 ounces, 0.057 grams
- Marking: 811D



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

1A

PARAMETER	SYMBOL	LIMIT	UNITS
Collector-Base Voltage	V_{CBO}	120	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current (DC)	I _C	1	Α
Collector Current (Pulse)	I _{CP}	3	Α
Power Dissipation	P _D	1.4	W
Junction Temperature	T_J	150	°C
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	°C
Thermal Resistance from Junction to Ambient (Note)	$R_{\theta JA}$	89	°C/W

Note: Mounted on FR4 PCB at 1 inch square copper pad.





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
OFF Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C = 10mA, I _B = 0A	100	-	-	V
Collector-Base Breakdown Voltage	BV _{CBO}	I _C = 0.1mA, I _E = 0A	120	-	-	V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = 0.1mA, I _C = 0A	6	-	-	V
Collector Cutoff Current	I _{CBO}	V _{CB} = 80V, I _E = 0A	-	-	100	nA
Emitter Cutoff Current	I _{EBO}	V_{EB} = 6V, I_{C} = 0A	-	-	100	nA
ON characteristics						
DC Current Gain (Note1)	h _{FE}	V_{CE} = 2V, I_{C} = 5mA	100	-	-	-
		$V_{CE} = 2V, I_{C} = 150mA$	100	-	250	
		V_{CE} = 2V, I_{C} = 500mA	40	-	-	
Collector-Emitter Saturation Voltage (Note1)	V _{CE(SAT)}	I _C = 0.1A, I _B = 10mA	-	60	120	mV
		I_{C} = 0.5A, I_{B} = 50mA	-	150	350	
		I _C = 1A, I _B = 0.1A	-	250	500	
Base-Emitter Saturation voltage	V _{BE(SAT)}	I _C = 0.1A, I _B = 10mA	-	-	1.0	
(Note1)		I _C = 0.5A, I _B = 50mA	-	-	1.1	V
Transition Frequency	f _T	V_{CE} = 5V, I_{E} = -50mA	100	-	-	MHz
Collector Output Capacitance	Сов	V_{CB} = 10V, I_E = 0A, f =1MHz	-	-	10	pF

Note: 1. Pulse width<a>300us, Duty cycle<a>2%





TYPICAL CHARACTERISTIC CURVES

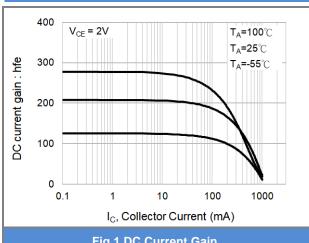


Fig.1 DC Current Gain

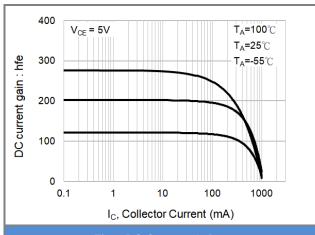


Fig.2 DC Current Gain

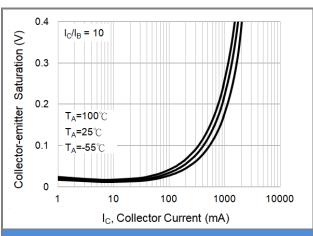


Fig.3 Collector-Emitter Saturation Voltage

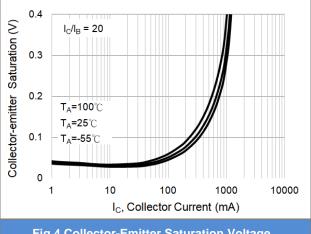
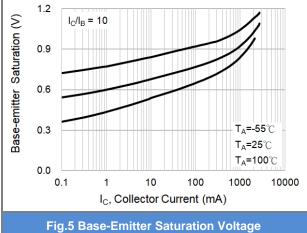


Fig.4 Collector-Emitter Saturation Voltage



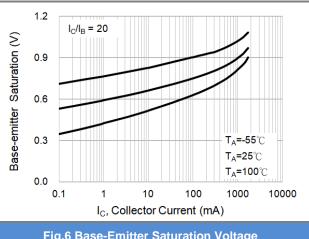


Fig.6 Base-Emitter Saturation Voltage





TYPICAL CHARACTERISTIC CURVES

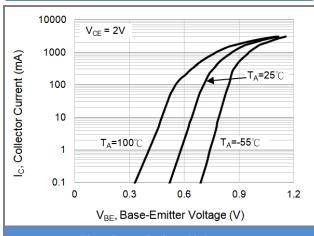
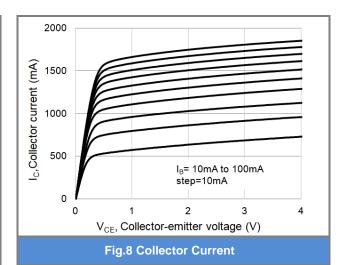
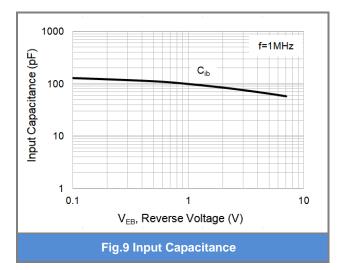
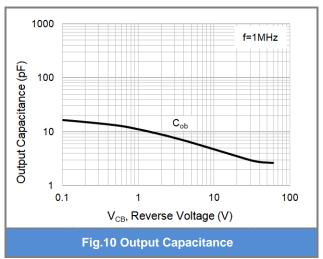
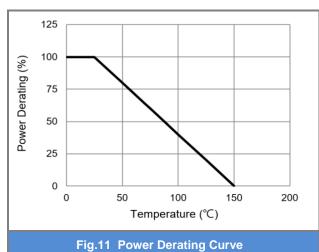


Fig.7 Base-Emitter Voltage









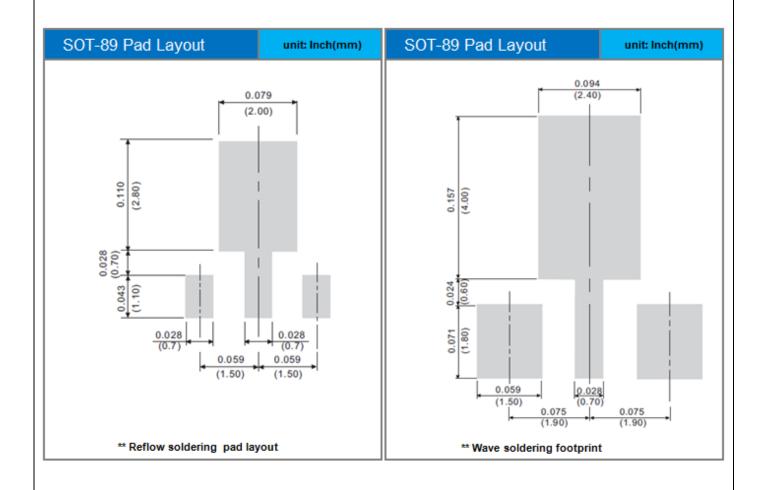




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
BCX56-16-AU_R1_000A1	SOT-89	1,000 pcs / 7" reel	811D	Halogen free

MOUNTING PAD LAYOUT







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